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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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## RENESAS

# MOS FIELD EFFECT TRANSISTOR NP82N03PUG

### SWITCHING N-CHANNEL POWER MOS FET

#### DESCRIPTION

The NP82N03PUG is N-channel MOS Field Effect Transistor designed for high current switching applications.

#### **FEATURES**

- Channel temperature 175 degree rating
- Super low on-state resistance
- $R_{DS(on)}$  = 2.8 m $\Omega$  MAX. (V<sub>GS</sub> = 10 V, I<sub>D</sub> = 41 A)
- Low Ciss: Ciss = 6050 pF TYP.

#### ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	VDSS	30	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	D(DC)	±82	А
Drain Current (pulse) Note1	D(pulse)	±328	А
Total Power Dissipation ( $T_A = 25^{\circ}C$ )	PT1	1.8	W
Total Power Dissipation (Tc = $25^{\circ}$ C)	Pt2	143	W
Channel Temperature	Tch	175	°C
Storage Temperature	Tstg	–55 to +175	°C
Repetitive Avalanche Current Note2	lar	47	А
Repetitive Avalanche Energy Note2	Ear	221	mJ

**Notes 1.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%

**2.** T<sub>ch</sub>  $\leq$  150°C, V<sub>DD</sub> = 15 V, R<sub>G</sub> = 25  $\Omega$ , V<sub>GS</sub> = 20  $\rightarrow$  0 V

#### THERMAL RESISTANCE

Channel to Case Thermal Resistance	Rth(ch-C)	1.05	°C/W
Channel to Ambient Thermal Resistance	Rth(ch-A)	83.3	°C/W

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#### ORDERING INFORMATION

PART NUMBER	PACKAGE		
NP82N03PUG	TO-263 (MP-25ZP)		



(TO-263)

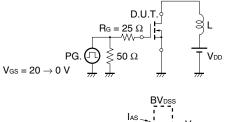
ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V			1.0	μA
Gate Leakage Current	lgss	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±100	nA
Gate to Source Threshold Voltage Note	VGS(th)	$V_{DS}$ = $V_{GS}$ , ID = 250 $\mu$ A	2.0	3.0	4.0	V
Forward Transfer Admittance Note	y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 41 A	19	39		S
Drain to Source On-state Resistance Note	RDS(on)	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 41 A		2.1	2.8	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 25 V		6050	9080	pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		700	1050	pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		480	870	pF
Turn-on Delay Time	td(on)	V <sub>DD</sub> = 15 V, I <sub>D</sub> = 41 A		39	90	ns
Rise Time	tr	V <sub>GS</sub> = 10 V		122	310	ns
Turn-off Delay Time	td(off)	R <sub>G</sub> = 0 Ω		70	140	ns
Fall Time	tr			15	40	ns
Total Gate Charge	QG	V <sub>DD</sub> = 24 V		106	160	nC
Gate to Source Charge	QGS	V <sub>GS</sub> = 10 V		28		nC
Gate to Drain Charge	Qgd	I <sub>D</sub> = 82 A		39		nC
Body Diode Forward Voltage Note	VF(S-D)	IF = 82 A, VGS = 0 V		0.9	1.5	V
Reverse Recovery Time	trr	IF = 82 A, VGS = 0 V		44		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/ <i>µ</i> s		41		nC

Note Pulsed

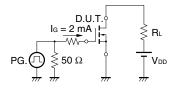
#### TEST CIRCUIT 1 AVALANCHE CAPABILITY

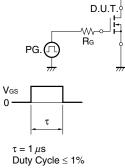
#### **TEST CIRCUIT 2 SWITCHING TIME**

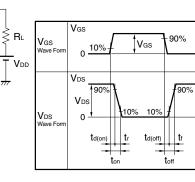




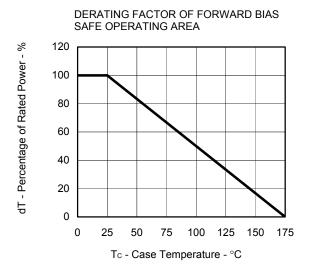
#### TEST CIRCUIT 3 GATE CHARGE

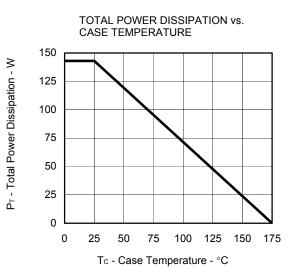




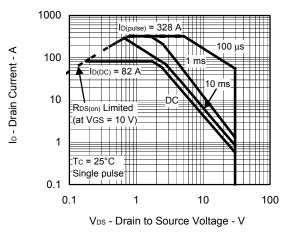


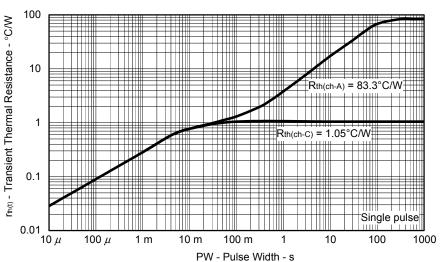
#### TYPICAL CHARACTERISTICS ( $T_A = 25^{\circ}C$ )



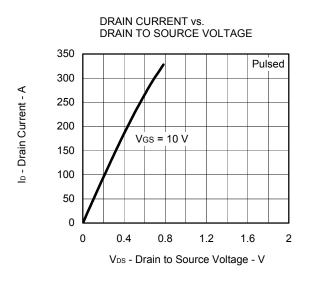




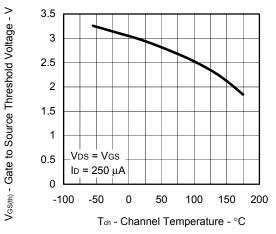




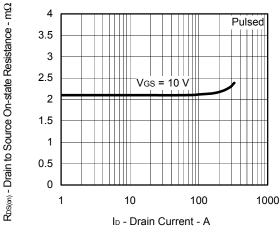
#### TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



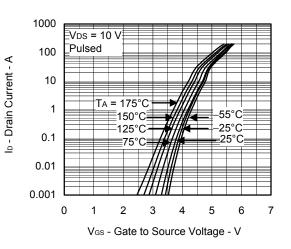
GATE TO SOURCE THRESHOLD VOLTAGE vs. CHANNEL TEMPERATURE



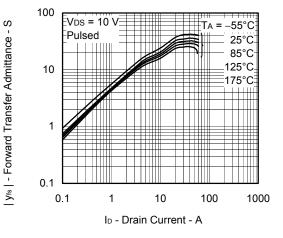
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



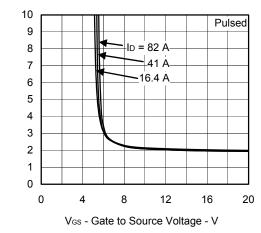
FORWARD TRANSFER CHARACTERISTICS



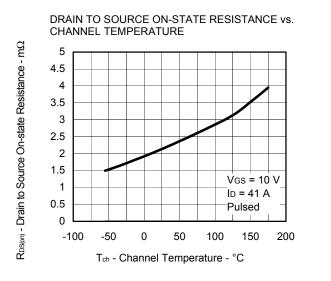
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



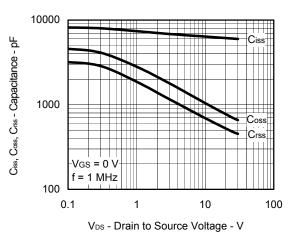
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



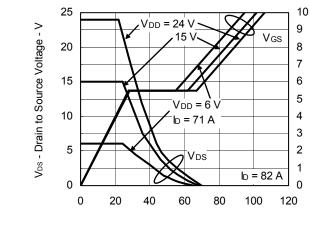
RDS(cn) - Drain to Source On-state Resistance - mΩ



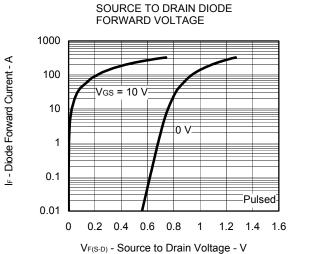
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



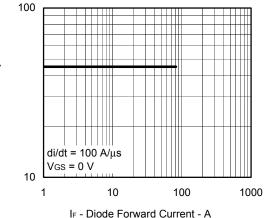
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



QG - Gate Charge - nC



**REVERSE RECOVERY TIME vs.** DIODE FORWARD CURRENT



Vdd = 15 V

Vgs = 10 V-

Rg = 0 Ω

1

ID - Drain Current - A

SWITCHING CHARACTERISTICS

td(off)

tr

10

td(on)

tr

100

td(on), tr, td(off), tr - Switching Time - ns

1000

100

10

1

0.1

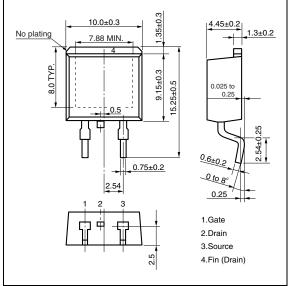


tr - Reverse Recovery Time - ns

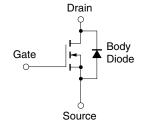
V<sub>GS</sub> - Gate to Source Voltage - V

#### PACKAGE DRAWING (Unit: mm)





#### **EQUIVALENT CIRCUIT**



**Remark** Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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